Size effects on Debye temperature, Einstein temperature, and volume thermal expansion coefficient of nanocrystals

C.C. Yang\textsuperscript{a,b}, M.X. Xiao\textsuperscript{a,b}, W. Li\textsuperscript{c}, Q. Jiang\textsuperscript{a,b,*}

\textsuperscript{a} Key Laboratory of Automobile Materials (Jilin University), Ministry of Education, Changchun 130022, China
\textsuperscript{b} Department of Materials Science and Engineering, Jilin University, Changchun 130022, China
\textsuperscript{c} Department of Mechanical Engineering, University of Alberta, Edmonton, AB, T6G 2G8, Canada

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Abstract

Based on a size-dependent root of mean square amplitude (rms) model, the size-dependent Debye temperatures of nanocrystals are modeled without any adjustable parameter by considering both Lindemann’s criterion and Mott’s equation. In terms of this model, the Debye temperatures depend on both size and interface conditions, which lead to related applications on size effects of the Einstein temperature and the volume thermal expansion coefficient. It is found that the model’s predictions are in good agreement with available experimental and computer simulation results.

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1. Introduction

The physical properties of nanocrystals have been investigated extensively both theoretically and experimentally due to their scientific and industrial importance [1]. As the size of low-dimensional materials decreases to the nanometer size range, the electronic, magnetic, optic, catalytic, and thermodynamic properties of the materials are significantly altered from those of either the bulk or a single molecule [1]. Among these properties of nanocrystals, the Debye temperature of nanocrystals, \( \Theta_D(D) \), has received considerable attention, since it is an essential physical quantity to characterize many material properties, such as the thermal vibration of atoms and phase transitions, where \( D \) denotes the diameter of nanoparticles and nanowires or the thickness of thin films [2–12]. Moreover, some important physical properties and their size effects, such as the Einstein temperature \( \Theta_E(D) \) and the volume thermal expansion coefficient \( \alpha_v(D) \), are all related to the \( \Theta_D(D) \) function [4,7,13]. Once the \( \Theta_D(D) \) function is known, the other two can be determined. Therefore, it is important to determine this function.

It is now known that the above physical properties of a free nanocrystal decrease as its \( D \) decreases [2,7,9,13], while they can decrease or increase for nanocrystals embedded in a matrix or deposited on a substrate [3–6,8,10–12]. A body of evidence shows that enhancement or depression of the foregoing physical properties of nanocrystals in a matrix essentially depends on the chemical interaction at interfaces between embedded nanocrystals and the matrix [3–6,8,10–12]. For instance, when the interfaces are coherent or semi-coherent, which denotes a strong bond connection, the enhancement of \( \Theta_D \) of the nanocrystals is present [11,12]. Although size effects on all of the above physical properties have been modeled separately by a series of related theoretical approaches, consistent insight and a systematic thermodynamic treatment considering both the size and interface effects are highly desirable in order to reveal the physical nature of the nanocrystals.

In this contribution, \( \Theta_D(D) \) functions of nanocrystals are modeled in the form of the root of mean square amplitude (rms) model. The model that is established is extended to predict the size effects on \( \Theta_E \) and \( \alpha_v \) of nanocrystals. The model
predictions agree well with known experimental and computer simulation results.

2. Model

In terms of the Debye model, the \( \Theta_D \) function is related to the rms \( \sigma \) by [4,14],

\[
\sigma^2 \propto T/\Theta_D^3
\]

(1)

when \( T > \Theta_D(\infty)/2 \), where \( T \) is the temperature and \( \infty \) denotes the bulk size.

According to Lindemann’s criterion [15] for melting and Mott’s equation [16,17], the size-dependent rms \( \sigma(D) \) has been found to have the following form [14,18]:

\[
\sigma(D)/\sigma(\infty) = \exp[(\alpha - 1)/\{D/\Theta(D) - 1\}] \]

(2)

where \( \alpha = \sigma^2_\alpha(D)/\sigma^2(\infty) \), with \( \sigma_\alpha(D) \) and \( \sigma(\infty) \) denoting size-dependent rms values of the surface and interior atoms of nanocrystals, respectively [14,18], and \( \Theta(D) \) shows a critical diameter at which all atoms of a low-dimensional material are located on its surface, which depends on dimension \( d \) and atomic diameter \( h \) through [14,19],

\[
D_0 = 2(3-d)h
\]

(3)

where \( d = 0 \) for nanoparticles, \( d = 1 \) for nanowires, and \( d = 2 \) for thin films.

In Eq. (2), the parameter \( \alpha \) must be known to determine \( \sigma(D) \). For crystals with free surfaces, such as free-standing particles, particles or thin films deposited on inert substrates, and nanowires in inert porous glasses, their \( \sigma^2(D) > \sigma^2(\infty) \) and \( \alpha > 1 \) [14], and [14,19],

\[
\alpha = [2\Delta S_{\text{vib}}(\infty)/(3R)] + 1
\]

(4)

where \( R \) is the ideal gas constant and \( \Delta S_{\text{vib}}(\infty) \) is the vibrational part of the overall melting entropy \( \Delta S_m(\infty) \), which consists of at least three components: positional \( \Delta S_{\text{pos}}(\infty) \), vibrational \( \Delta S_{\text{vib}}(\infty) \), and electronic \( \Delta S_{\text{el}}(\infty) \) [17]. Namely,

\[
\Delta S_m(\infty) = \Delta S_{\text{vib}}(\infty) + \Delta S_{\text{pos}}(\infty) + \Delta S_{\text{el}}(\infty)
\]

and

\[
\Delta S_{\text{pos}}(\infty) = -R(x_A \ln x_A + x_B \ln x_B),
\]

where \( x_A \) and \( x_B \) are molar fractions of crystals and vacancies, respectively [17]. For the melting transition, \( x_A = 1/(1 + \Delta V_m/V_s) \), \( x_B = 1 - x_A \), where \( \Delta V_m = V_i - V_s \), with \( V \) being the molar volume and the subscripts \( s \) and \( i \) denoting the crystal and the liquid, respectively. For metallic crystals, the type of chemical connection does not vary during the melting transition. Thus,

\[
\Delta S_{\text{el}}(\infty) \approx 0
\]

and \( \Delta S_{\text{vib}}(\infty) = \Delta S_m(\infty) - \Delta S_{\text{pos}}(\infty), \) or

\[
\Delta S_{\text{vib}}(\infty) = \Delta S_m(\infty) + R(x_A \ln x_A + x_B \ln x_B).
\]

(5)

However, for semi-metals, \( \Delta S_{\text{el}}(\infty) \) strongly contributes to \( \Delta S_m(\infty) \). In this situation, \( \Delta S_{\text{vib}}(\infty) \) is determined by Mott’s equation [16],

\[
\Delta S_{\text{vib}}(\infty) = 3R \ln(v_s/v_i) = (3/2)R \ln(c_i/c_f)
\]

(6)

where \( v \) and \( c \) denote the characteristic vibration frequency and electrical conductivity, respectively.

For nanocrystals embedded in a matrix with a coherent or semi-coherent interface, their \( \sigma^2(D) < \sigma^2(\infty) \) and \( \alpha < 1 \) [19], and [19],

\[
\alpha = [(h_M/h)^2T_m(\infty)/T_M(\infty) + 1]/2,
\]

(7)

where \( h_M \) denotes the atomic diameter of the matrix, and \( T_m(\infty) \) and \( T_M(\infty) \) are the bulk melting temperature of the nanocrystals and the matrix, respectively.

Based on Eq. (1), it is assumed that \( \Theta_D(D) \) has the same size dependence of \( 1/\sigma(D) \) as a first-order approximation, since the nature of any phase transition is related to the potentials of the two related phases of the crystals. Thus,

\[
\Theta_D(D)/\Theta_D(\infty) = \sigma(\infty)/\sigma(D).
\]

(8)

Substituting Eq. (2) into Eq. (8), this reads,

\[
\Theta_D(D)/\Theta_D(\infty) = \exp[-(\alpha - 1)/\{D/\Theta(D) - 1\}].
\]

(9)

Since \( \Theta_E(\infty) \propto \Theta_D(\infty) \) [4] and \( \alpha_e(\infty) \propto 1/\Theta_D^2(\infty) \) [7], Eq. (9) can be extended for \( \Theta_E(D) \) and \( \alpha_e(D) \) functions as follows:

\[
\Theta_E(D)/\Theta_E(\infty) = \exp[(\alpha - 1)/\{D/\Theta(D) - 1\}].
\]

(10)

\[
\alpha_e(D)/\alpha_e(\infty) = \exp[(\alpha - 1)/\{D/\Theta(D) - 1\}].
\]

(11)

3. Results and discussion

Comparisons between model predictions in terms of Eqs. (4), (7) and (9) and the available experimental and computer simulation results for \( \Theta_D(D) \) functions of Fe, \( \beta \)-Sn, Se, Cu, Co, Au, and Ar/Al (Ar nanocrystals embedded in Al matrix) nanocrystals are shown in Fig. 1, where the related parameters are listed in Table 1 (parameters used for other figures are also listed in this table). It is obvious that our model predictions for different kinds of nanocrystals in different surroundings correspond to the experimental and computer simulation results in the full size range, which implies that Eq. (9) is reasonable.

As shown in Fig. 1(a)–(f), \( \Theta_D(D) \) with \( \alpha > 1 \) decreases for free nanocrystals as \( D \) decreases. \( \alpha > 1 \) implies a decrease in \( \Theta_D(D) \) with an increase in the rms. Note that Fe and \( \beta \)-Sn films in Fig. 1(a) and (b) may refer to fine granular structures with high densities of inner surface/grain boundaries and cannot be described by a continuous film [14]. This granular structure is similar to a random structure of a chain polymer, modeled by the trajectory of a self-avoiding walk with a fractal dimension of \( d = 4/3 \) [14]. It is obvious that the depression for \( \Theta_D(D) \) of films with \( D \) is weaker than that of nanoparticles, as shown in Fig. 1(a) and (b), which is induced by different values of \( d \) and thus different values of \( D_0 \) in Eq. (3). Consequently, our model can also predict the dimension dependence of \( \Theta_D(D) \), while different dimensions of nanocrystals have different surface/volume ratios.

For nanocrystals embedded in a matrix with a coherent or semi-coherent interface, such as the Ar/Al system in Fig. 1(g), \( \Theta_D(D) \) with \( \alpha < 1 \) increases as \( D \) decreases. \( \alpha < 1 \) implies the suppression of the rms of the nanoparticles
as a total effect induced by both the surface and the interface. Although the surface of the nanocrystals still has
a tendency to lower the $\Theta_D(D)$ value, the total effect of the surface and the interface between the nanocrystals and
the matrix leads to a drop in the internal energy of the nanocrystals and thus an increase in $\Theta_D(D)$ as $D$ decreases.
Note also that $h_M < h$ in the system reported above, although it is not a necessary condition for $\alpha < 1$ in

Table 1

<table>
<thead>
<tr>
<th>Material</th>
<th>$\Theta_D(\infty)$</th>
<th>$T_m(\infty)$ [20]</th>
<th>$\Delta H_m(\infty)$ [20]</th>
<th>$\Delta V_m/V_s$ [21] (%)</th>
<th>$\Delta S_{\text{vib}}(\infty)$ K</th>
<th>$h$ [22]</th>
</tr>
</thead>
<tbody>
<tr>
<td>Fe</td>
<td>388.00 [4]</td>
<td>1811.00</td>
<td>13.80</td>
<td>3.4</td>
<td>6.42$^a$</td>
<td>0.2482</td>
</tr>
<tr>
<td>$\beta$-Sn</td>
<td>140.00 [6]</td>
<td>505.08</td>
<td>5.40</td>
<td>10.93$^b$</td>
<td>0.3181</td>
<td></td>
</tr>
<tr>
<td>Se</td>
<td>135.90 [7]</td>
<td>494.00</td>
<td>5.40</td>
<td>10.93$^b$</td>
<td>0.4366 [7]</td>
<td></td>
</tr>
<tr>
<td>Cu</td>
<td>343.00 [8]</td>
<td>1357.77</td>
<td>5.40</td>
<td>8.08$^a$</td>
<td>0.2556</td>
<td></td>
</tr>
<tr>
<td>Co</td>
<td>400.00 [9]</td>
<td>1768.00</td>
<td>5.40</td>
<td>7.83$^a$</td>
<td>0.2507</td>
<td></td>
</tr>
<tr>
<td>Au</td>
<td>184.59 [10]</td>
<td>1337.33</td>
<td>5.40</td>
<td>7.74$^a$</td>
<td>0.2884</td>
<td></td>
</tr>
<tr>
<td>Ar</td>
<td>70.00 [11]</td>
<td>83.80</td>
<td>5.40</td>
<td>7.74$^a$</td>
<td>0.3650 [11]</td>
<td></td>
</tr>
<tr>
<td>Pb</td>
<td>600.61</td>
<td>4.77</td>
<td>3.5</td>
<td>6.71$^a$</td>
<td>0.3500</td>
<td></td>
</tr>
</tbody>
</table>

$\Theta_D(\infty)$ and $T_m(\infty)$ are in K, the bulk melting enthalpy $\Delta H_m(\infty)$ in kJ mol$^{-1}$, $\Delta S_{\text{vib}}(\infty)$ in J mol$^{-1}$ K$^{-1}$, and $h$ is in nm.

$^a$ The values are calculated by Eq. (5), where $\Delta S_{\text{m}}(\infty) = \Delta H_m(\infty)/T_m(\infty)$ and $R = 8.314$ J mol$^{-1}$ K$^{-1}$.

$^b$ The value is determined by Eq. (6) with $c_s/c_l = 2.10$ [17].

$^c$ The values are approximately equal to $\Delta S_{\text{m}}(\infty)$ [19].
and (b), comparisons between the model predictions and the available experimental results for the 
Fig. 2, where (a).
Fig. 3, where

where $\alpha_{\text{Se}}(D)$ is found to be a second-order approximation, $\alpha_{\text{Se}}(D) \approx 3\alpha_{\text{Se}}(D)$ could collapse in a smaller size range (such as $D = 16$ nm). As mentioned above, $\alpha_{\text{Se}}(D)$ increases with decreasing $D$. It is known that $E_c \approx 1/\alpha_{\text{Se}}$, where $E_c$ denotes the cohesive energy of atoms [13] and $E_c(D)$ decreases with decreasing $D$ [24], which confirms Eq. (11).

Note that, in the above consideration, the effect of size on $h$ has been neglected, i.e. $V_s$ or $h$ is assumed to be a size-independent constant, namely $\Delta V_s = V_s(\infty) - V_s(D) \approx 0$ or $\Delta h = h(\infty) - h(D) \approx 0$. It is known that $\Delta d = h(\infty) - h(D) \approx 0$. Thus, $V_s(D)/V_s(\infty) = 0.1\%–2.5\%$ when $D < 20$ nm, and it is negligible when $D > 20$ nm [25]. Thus, even for $D < 20$ nm, $V_s(D)/V_s(\infty) \approx 0.95–0.97$. According to Lindemann’s criterion, $\Theta_D = c_1(T_m/(MV_s^{2/3}))^{1/2}$ [26], where $c_1$ is a constant and $M$ denotes the molar weight and is size-independent.

Thus, $T_m(\infty) \approx \Theta_D^{2/3}(V_s(\infty))^{2/3}$. If $T_m(D)$ has the same size dependence of $\Theta_D^{2/3}(V_s(\infty))^{2/3}$ as a first-order approximation, $T_m(D)/T_m(\infty) \approx \Theta_D^{2/3}(V_s(\infty))^{2/3}$. Similarly, $\alpha_{\text{Se}}(D)/\alpha_{\text{Se}}(\infty) \approx (\Theta_D^{2/3}(V_s(\infty))^{2/3})/([V_s(D)/V_s(\infty)]^{2/3}$, since $\Theta_D = c_2/(\alpha_{\text{Se}}MV_s^{2/3})^{1/2}$, with $c_2$ being a constant [7].

Thus, the error range induced by $[V_s(D)/V_s(\infty)]^{2/3}$ is only $3\%–5\%$ for the $T_m(D)$ function in our former prediction [14,19] and for the $\alpha_{\text{Se}}(D)$ function in the present prediction. This high-order error has also been neglected for simplicity in Ref. [18].

As shown above, $\Theta_D(D)$, $\Theta_E(D)$, and $\alpha_{\text{Se}}(D)$ functions for different kinds of nanocrystals and different surroundings can be described as long as the related thermodynamic parameters of crystals are known. The physical nature of the enhancement or suppression of these physical properties is related to both the surface/volume ratio and the interfacial energetic change between embedded nanocrystals and the matrix.

4. Conclusions

In summary, a model for the $\Theta_D(D)$ function is established by considering both Lindemann’s criterion and Mott’s equation. The $\Theta_D(D)$ function decreases for free nanocrystals and increases for nanocrystals having a strong chemical interaction with their surroundings as $D$ decreases. Since the $\Theta_D(D)$ and $\alpha_{\text{Se}}(D)$ functions have simple relations to the $\Theta_D(D)$ function, these functions are also developed. The model’s predictions correspond to known experimental and computer simulation results.

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